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DATE MAILED: 03/10/2005

10/809,891 03/26/2004 Fuja Shone LEE.009 7786					
	10/809,891	03/26/2004	Fuja Shone	LEE.009	7786
20987 7590 03/10/2005 EXAMINER	20987	7590 03/10/2005		EXAM	INER
VOLENTINE FRANCOS, & WHITT PLLC BOOTH, RICHARD A	ONE FREEDOM SQUARE			BOOTH, RICHARD A	
ONE FREEDOM SQUARE 11951 FREEDOM DRIVE SUITE 1260 ART UNIT PAPER NUMBER				ART UNIT	PAPER NUMBER
RESTON, VA 20190 2812				2812	•

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	10/809,891	SHONE, FUJA			
Office Action Summary	Examiner	Art Unit			
•	Richard A. Booth	2812			
The MAILING DATE of this communication ap		!			
Period for Reply					
A SHORTENED STATUTORY PERIOD FOR REPI THE MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a re - If NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statu Any reply received by the Office later than three months after the maili earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, may a reply be tin ply within the statutory minimum of thirty (30) day d will apply and will expire SIX (6) MONTHS from te, cause the application to become ABANDONE	nely filed s will be considered timely. the mailing date of this communication. D (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 10	February 2005.				
2a) This action is FINAL . 2b) ⊠ Th	This action is FINAL. 2b)⊠ This action is non-final.				
	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims		•			
4) ☐ Claim(s) 1-20 is/are pending in the application 4a) Of the above claim(s) 6-20 is/are withdray 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-5 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/	vn from consideration.				
Application Papers					
9)☐ The specification is objected to by the Examir	ner.				
10)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.					
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).					
Replacement drawing sheet(s) including the corre					
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of: 1. Certified copies of the priority document copies of the priority document copies of the certified copies of the priority document copies of the certified copies of the priority document copies of the certified copies of the priority document copies of the certified copies of the priority copies of the certified copies of the priority copies of the pri	nts have been received. nts have been received in Applicat iority documents have been receive au (PCT Rule 17.2(a)).	ion No ed in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892)	4) 🔲 Interview Summary	r (PTO-413)			
 Notice of Neterences Cited (170-032) Notice of Draftsperson's Patent Drawing Review (PTO-948) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/0 Paper No(s)/Mail Date 03/26/04. 	Paper No(s)/Mail D				

DETAILED ACTION

· Election/Restrictions

Applicant's election with traverse of the first embodiment in the reply filed on 2/10/05 is acknowledged. The traversal is on the ground(s) that the first and third embodiments are not mutually exclusive. This is not found persuasive because if claim 1 which is generic to the first and third embodiments is found to be allowable, claim 6 will also be found allowable but until that time claim 6 will not be examined on the merits.

The requirement is still deemed proper and is therefore made FINAL.

Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

Claim 1 is rejected under 35 U.S.C. 102(b) as being anticipated by Hopper et al., U.S. Patent 6,406,960.

Hopper et al. shows the invention as claimed including a method of forming an oxide-nitride-oxide layer in a non-volatile memory device, comprising the steps of: providing a silicon substrate 16; forming a bottom oxide 28 on the silicon substrate; depositing a silicon-rich silicon nitride layer 30 on the bottom oxide layer; and performing an oxidation process to react with silicon atoms in the silicon-rich nitride

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layer, so as to form a top oxide layer 32 (see figs. 1-4 and col. 4-line 10 to col. 5-line 59).

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 3-5 are rejected under 35 U.S.C. 103(a) as being unpatentable over Hopper et al., U.S. Patent 6,406,960 in view of Sato, U.S. Patent 4,720,323.

Hopper et al. is applied as above but fails to expressly disclose wherein the silicon nitride layer is between 10 and 200 angstroms, wherein the oxidation process is conducted at a temperature between seven hundred and eleven hundred celsius, and where the top oxide layer is between twenty to two hundred angstroms.

Sato discloses a memory device with an ONO layer where the silicon nitride layer 39 has a thickness of 150 angstroms, where the oxidation process is conducted at nine hundred fifty celsius, and where the top oxide layer 40 is sixty angstroms (see col. 4-lines 53-64). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the process of Hopper et al. so as to form the nitride and oxide layers at the thickness as suggested by Sato and perform the oxidation process at the temperature suggested by Sato because these are suitable temperatures and thicknesses for ONO dielectrics in memory devices.

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Claim 2 is rejected under 35 U.S.C. 103(a) as being unpatentable over Hopper et al., U.S. Patent 6,406,960 in view of Chang et al., U.S. Patent 5,836,772.

Hopper et al. is applied as above but fails to expressly disclose wherein the bottom oxide layer is between 10 and 100 angstroms.

Chang et al. discloses wherein the bottom oxide layer in an ONO structure is between twenty-five to one hundred angstroms (see fig. 1). In view of this disclosure, it would have been obvious to one of ordinary skill in the art at the time the invention was made to modify the process of Hopper et al. so as to form the bottom oxide layer to the thickness specified in Chang et al. because Chang et al. shows this to be a suitable thickness for the bottom oxide layer of an ONO structure in memory devices.\

Conclusion

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Richard A. Booth whose telephone number is (571) 272-1668. The examiner can normally be reached on Monday-Thursday from 7:30-6:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Michael Lebentritt can be reached on (571) 272-1873. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the

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Krichard A. Booth Primary Examiner Page 5

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March 4, 2005